Strain tuned topology in the Haldane and the modified Haldane models

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We study the interplay between a uniaxial strain and the topology of the Haldane and the modified Haldane models which, respectively, exhibit chiral and antichiral edge modes. The latter were, recently, predicted by Colomés and Franz (Phys. Rev. Lett. 120, 086603 (2018)) and expected to take place in the transition metal dichalcogenides. Using the continuum approximation and a tight-binding approach, we investigate the effect of the strain on the topological phases and the corresponding edge modes. We show that the strain could induce transitions between topological phases with opposite Chern numbers or tune a topological phase into a trivial one. As a consequence, the dispersions of the chiral and antichiral edge modes are found to be strain dependent. The strain may reverse the direction of propagation of these modes and eventually destroy them. This effect may be used for strain-tunable edge currents in topological insulators and two-dimensional transition metal dichalcogenides.

I. INTRODUCTION

Topological insulators were first introduced by Haldane in his seminal paper\(^1\) where he showed that the Hall conductance may be quantized in the absence of an external magnetic field, which is known as the Quantum Anomalous Hall (QAH) effect\(^2\). The latter arises as an intrinsic property of the electronic band structure. Haldane proposed a two-band spinless fermion model on a honeycomb lattice with local magnetic fluxes, breaking the time reversal symmetry (TRS), and arranged in a geometry resulting in a zero net flux per unit cell. The key parameters of the model are the Semenoff\(^3\) mass \(M\) and the complex second nearest neighbor hopping integrals \(t_{2\pm1}^\Phi\). The sublattice potential \(\pm M\), describing the masses of the two atoms, forming the lattice, is responsible for the inversion symmetry breaking while the complex hopping terms break the TRS due to the phase \(\Phi\) acquired in the presence of the local magnetic fluxes. By tuning the values of \(M\) and \(\Phi\), the ground state of the system undergoes transitions between phases with different topology characterized by a topological invariant, known as the first Chern number \(C\).\(^4\) A Trivial, or band, insulating state corresponds to \(C = 0\) while a topological, or a Chern, insulator is described by a non-vanishing Chern number, which is \(C = \pm 1\) in the case of the Haldane model (HM). Large Chern numbers are expected by taking into account distant neighbor hopping terms\(^5\).

Besides the non-vanishing Chern number, the topological signature of a phase is marked by the presence of chiral edge states crossing the bulk gap of the band structure of a finite size system, as those found in the quantum Hall effect\(^6\). These edge states are at the origin of the substantial interest devoted to the QAH effect considered as a suitable candidate to pave the way for dissipationless electronic applications in the absence of a magnetic field\(^7\).

Regarding the difficulty to fulfill the local magnetic flux requirements, the HM is, as stated by Haldane, un-lkeely to be realized in condensed matter\(^1\). The first realization of the HM was achieved with cold atoms in a shaking optical lattice\(^8\). The Fe-based honeycomb ferromagnetic insulators are also expected to be described by the HM\(^9\). The experimental realization of the QAH effect predicted by Haldane, became possible only after the prediction of the quantum spin Hall (QSH) effect, resulting from the generalization of the HM to the spin-full system with TRS invariance\(^10\). This effect led to the discovery of the topological insulators considered as one of the hottest topics of interest in condensed matter physics\(^11\). Several observations of QAH effect have been reported in magnetic topological insulators\(^16\)–\(^18\).

To understand the fundamental aspects of the QAH effect it is necessary to uncover its dependence on the different external and intrinsic factors such as doping\(^19\)–\(^20\), disorder\(^21\)–\(^23\), temperature\(^24\), interaction\(^25\)–\(^26\), magnetic-electric fields\(^27\), material thickness\(^28\), mechanical strain\(^25\)–\(^32\). In particular, the latter is found to be a useful tool to tune the electronic band structure of graphene\(^33\) and topological insulators\(^25\)–\(^26\),\(^34\)–\(^40\). Recently, the effect of a nonuniform strain on ribbons described by the HM was investigated within the tight-binding (TB) approach\(^32\). The authors showed that the strain does not affect the topological phases and the dispersion of the corresponding edge states.

However, strain is found to be a substantial parameter to tune the properties of topological insulators\(^25\)–\(^26\),\(^34\)–\(^39\) and to induce helical edge states in armchair graphene nanoribbon\(^41\). Contrary to the chiral edge modes, occurring in systems with broken TRS, the helical edge states appear in systems where TRS is preserved, as in QSH effect\(^11\). As the chiral modes of the spinless QAH effect, the helical edge states propagate in opposite direction for a given spin.

Recently, antichiral edge modes were proposed to occur in 2D semi-metal\(^12\), where co-propagating modes appear at the parallel edges of the system, and are counter-balanced by gapless bulk states. These edge states can be obtained
in zigzag graphene nanoribbon described by the so-called modified Haldane model (mHM) where the Dirac points are offset in energy by a term $\pm 3\sqrt{3}t_2 \sin \Phi^{42,43}$.

In the present work, we raise the issue regarding the robustness of the topological phases of the HM and the mHM against a uniform uniaxial strain. We particularly, ask the following questions: Is it possible to tune, by the strain, the topology of these models? Could the direction of the propagation of the chiral and antichiral edge modes be controlled by the strain?

We first study the behavior of the Haldane phase diagram under a uniaxial strain using the continuum limit approximation and, then derive, within a TB approach, the strain dependence of the edge states of a zigzag nanoribbon described by the HM. In a second part, we consider the effect of the strain on the antichiral edge modes of the mHM.

The main results of this paper can be summarized as follows: (i) Contrary to a nonuniform deformation, a uniaxial strain could destroy a topological phase and tune it to a trivial insulating state. (ii) By adjusting the strain amplitude, the system can be driven from a topological phase to an other with opposite Chern number, which means that the strain may act on the edge current. (iii) At a tensile strain of 50%, transition between topological phases with opposite Chern numbers occurs on a line boundary and not only at the point $(M = 0, \Phi = 0)$ as found in the undeformed HM. (iv) The antichiral edge modes, of the mHM, are strain dependent with a switchable energy dispersion. Such effect, which may lead to a strain-tunable edge currents, could be realized in two-dimensional (2D) metal transition dichalcogenides, as WSe$_2$ showing edge states reminiscent of those of mHM$^{12}$.

The paper is organized as follows. In Sec. II, we describe the HM under uniaxial strain for an infinite honeycomb lattice, and then derive the strain dependence of the corresponding Chern number in the continuum limit. We then discuss the behavior of the phase diagram under the strain. In Sec. III, we consider, within the TB model, the effect of the strain on a zigzag nanoribbon described by the HM in the presence of a uniaxial strain applied along the armchair direction. We will focus on the behavior of the edge states as a function of the deformation. In Sec. IV, we discuss a zigzag graphene nanoribbon described by mHM under a uniaxial strain. We numerically determine, within the tight binding approach, the strain dependence of the corresponding antichiral edge mode. Sec. IV is devoted to the concluding remarks.

II. HALDANE MODEL UNDER UNIAXIAL STRAIN

A. Electronic Hamiltonian

We consider a honeycomb lattice, with two types of atoms (A and B), under a uniaxial strain applied along the armchair direction corresponding to the y axis (Fig.1). In the resulting quinoid lattice, the distance between nearest neighbor atoms, along the strain axis, changes from $a$ to $a' = a + \delta a = a(1+\epsilon)$ where $\epsilon = \frac{\delta a}{a}$ is the strain amplitude. For a compressive (tensile) deformation $\epsilon$ is negative (positive). It is worth to stress that we only consider the strain component $\epsilon_{yy} = \epsilon$ and neglect, for simplicity, the $\epsilon_{xx}$ term of the strain tensor. This assumption is justified in graphene since the corresponding Poisson ratio, relating the strain components $\epsilon_{xx} = -\nu \epsilon_{yy}$, is small ($\nu = 0.165$) and decreases with increasing strain amplitude$^{14}$.

![FIG. 1. Deformed honeycomb lattice along the armchair y axis. $(\tilde{a}_1, \tilde{a}_2)$ is the lattice basis. The hopping parameters to the first (second) neighbors $t$ and $t'$ ($t_1$ and $t_2'$) are different due to the deformation. Vectors connecting first (second) neighboring atoms are denoted $\vec{r}_1$ ($\vec{r}_2$). The phase pattern for the second-neighbour hopping parameters of the HM is also shown. The arrow indicate the directions along which the hopping integrals $t_2$ and $t_2'$ acquire positive phase $e^{i\Phi}$ and $e^{i\Phi'}$ respectively. The area of the unit cell is decomposed in regions denoted $a',a'', b, b'$ and c.](image-url)
where \( b = \sqrt{3}a \) and for graphene \( d = \frac{a}{2\sqrt{3}} \).

It is worth to note that, the Harrison law is not accurate beyond the linear elastic regime. For more accurate values of the hopping amplitudes, Density Functional Theory calculations were proposed\(^{17}\).

As in the HM, the hopping integrals \( t \) and \( t' \) between first neighboring atoms are real since the paths corresponding to these hops delimit a unit cell with a total zero magnetic flux\(^1\). However, the hopping matrix elements \( t_2 \) and \( t'_2 \) acquire a Peierls phases denoted respectively \( \Phi \) and \( \Phi' \). Figure 1 shows the directions along which the hopping integrals are either \( t_2 e^{i\Phi} \) or \( t'_2 e^{i\Phi'} \).

The \( \Phi \) phase is the same as that of the undeformed lattice since the area \( S \) constructed on the vectors \( \overrightarrow{x}_1 \) and \( \overrightarrow{x}_2 \) in unchanged under the uniaxial strain. However, the phase \( \Phi' \) is strain dependent since it is acquired along the path delimiting the surface \( S' \), constructed on the areas \( a', a'' \) and \( b' \), which is deformed under the strain: \( \Phi' = \frac{2\pi}{M} (\Phi_{a'} + \Phi_{b'} + \Phi_{a''}) \), where \( \Phi_{a'}, \Phi_{b'}, \) and \( \Phi_{a''} \) are the fluxes through the \( a' \), \( a'' \) and \( b' \) regions and \( \Phi_0 \) is the flux quantum. The flux area \( S' \) could be expressed as a function of the undeformed area \( S \) as \( S' = \frac{1}{2} |\overrightarrow{x}_1 \times \overrightarrow{x}_2| = (1 + \epsilon) S \), which means that:

\[
\Phi' = (1 + \epsilon) \Phi
\]

It is worth to stress that having \( \Phi' \neq \Phi \), in the presence of the strain, is not crucial to tune the topology by the strain as we will show in the following sections.

The electronic Hamiltonian of the strained lattice could be written, in the basis \( \{ |\Psi^{A_1}_{\vec{k}}\rangle, |\Psi^{B_1}_{\vec{k}}\rangle \} \) associated to the two atoms \( A \) and \( B \) of the unit cell, as

\[
H(\vec{k}) = \begin{pmatrix}
    h_{AA}(\vec{k}) & h_{AB}(\vec{k}) \\
    h_{BA}(\vec{k}) & h_{BB}(\vec{k})
\end{pmatrix}
\]

(6)

where

\[
h_{AA}(\vec{k}) = M + 2t_2 \left( \cos \Phi \cos \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \cos \Phi' (\cos \vec{k}.\vec{a}_2 + \cos \vec{k}.\vec{a}_3) \right) - 2t_2 \left( \sin \Phi \sin \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \sin \Phi' (\sin \vec{k}.\vec{a}_2 + \sin \vec{k}.\vec{a}_3) \right)
\]

\[
h_{BB}(\vec{k}) = -M + 2t_2 \left( \cos \Phi \cos \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \cos \Phi' (\cos \vec{k}.\vec{a}_2 + \cos \vec{k}.\vec{a}_3) \right) + 2t_2 \left( \sin \Phi \sin \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \sin \Phi' (\sin \vec{k}.\vec{a}_2 + \sin \vec{k}.\vec{a}_3) \right)
\]

\[
h_{AB}(\vec{k}) = t' e^{i\vec{k}.\vec{x}_3} + t (e^{i\vec{k}.\vec{x}_1} + e^{i\vec{k}.\vec{z}_2})
\]

(7)

\[
H(\vec{k}) = h_0(\vec{k})\sigma^0 + \sum_{i=1}^{3} h_i(\vec{k})\sigma^i
\]

(8)

with

\[
h_0(\vec{k}) = 2t_2 \left( \cos \Phi \cos \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \cos \Phi' (\cos \vec{k}.\vec{a}_2 + \cos \vec{k}.\vec{a}_3) \right)
\]

\[
h_{x}(\vec{k}) = t' \cos(\vec{k}.\vec{x}_3) + t \cos(\vec{k}.\vec{x}_1 + \cos \vec{k}.\vec{z}_2)
\]

\[
h_{y}(\vec{k}) = t' \sin(\vec{k}.\vec{x}_3) + t \sin(\vec{k}.\vec{x}_1 + \sin \vec{k}.\vec{z}_2)
\]

\[
h_{z}(\vec{k}) = M - 2t_2 \left( \sin \Phi \sin \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \sin \Phi' (\sin \vec{k}.\vec{a}_2 + \sin \vec{k}.\vec{a}_3) \right)
\]

(9)

The Hamiltonian given by Eq.8 is invariant under time reversal transformation if

\[
H^*(-\vec{k}) = H(\vec{k}) + 2 \left[ 2t_2 \left( \sin \Phi \sin \vec{k}.\vec{a}_1 + \frac{t'_2}{t_2} \sin \Phi' (\sin \vec{k}.\vec{a}_2 + \sin \vec{k}.\vec{a}_3) \right) \right] \sigma_3 = H(\vec{k})
\]

(10)

The eigenvalues of the Hamiltonian given by Eq.8 are:

\[
\epsilon_\lambda(\vec{k}) = h_0(\vec{k}) + |h(\vec{k})|,
\]

(11)

where \( \lambda = \pm \) is the band index. For \( M = 0 \) and \( \Phi = 0 \), one recovers the band structure of graphene under a uniaxial strain showing two bands touching at the Dirac points \( D \) and \( D' \) given by \( \vec{k}_{D,D'} = \left( k_x^\lambda,0 \right) \), where the
component $k_{\xi}^\xi$ at the valley $\xi = \pm$ is given by\(^{45}\)
\[
k_{\xi}^\xi = \xi \frac{2}{\sqrt{3}a} \arccos \left( -\frac{t'}{2t} \right).
\] (12)

Under the strain, the Dirac cones leave the high symmetry points $K$ and $K'$ and move towards each other, under a compressive strain ($\epsilon < 0$) and can, eventually, merge for $\epsilon = -0.5$.\(^{45}\)

To study the topological character of the HM under strain, one needs to determine the corresponding Chern number whose analytical expression could be derived taking the low energy form of the Hamiltonian of Eq.8, the so-called continuum limit.

**B. Chern number: continuum limit**

The Hamiltonian given by Eq.8 could be developed around the Dirac points as:
\[
H_{\xi}(\vec{q}) = \begin{pmatrix}
  m_{\xi} + \xi \hbar w_x q_x & \xi \hbar (w_x q_x - i\xi w_y q_y) \\
  \xi \hbar (w_x q_x + i\xi w_y q_y) & -\left( m_{\xi} - \xi \hbar w_0 q_x \right)
\end{pmatrix},
\] (13)

where $w_x$ and $w_y$ are the anisotropic Fermi velocities and $w_0$ is the tilt parameter, given by:
\[
w_x = \frac{3}{2} \frac{at}{\hbar} \left( 1 + \frac{2}{3} \xi \right), \quad w_y = \frac{3}{2} \frac{at}{\hbar} \left( 1 - \frac{4}{3} \xi \right)
\]
\[
w_0 = \frac{2\sqrt{3}a}{\hbar} \left( t_2 \cos \Phi \sin 2\theta + t'_2 \cos \Phi' \sin \theta \right),
\] (14)

where $\theta$ is defined as:
\[
\theta = \arccos \left( -\frac{t'}{2t} \right)
\] (15)

The mass term $m_{\xi}$ is:
\[
m_{\xi} = M + \xi 2t_2 \left( \frac{t'_2}{t_2} \sin \Phi' \sin \theta - \sin \Phi \sin 2\theta \right)
\] (16)

The dispersion relation reduces to:
\[
\epsilon_{\lambda}^{\xi}(\vec{q}) = \xi \hbar w_0 x q_x + \lambda \hbar \sqrt{w_x^2 q_x^2 + w_y^2 q_y^2 + m_{\xi}^2},
\] (17)

which describes massive Dirac fermions moving with anisotropic velocities along the $x$ and $y$ directions.

The topological character of a phase is determined by the first Chern number given by $C = C_{\xi} + C_{-\xi}$, where $C_{\xi}$ is the Chern number calculated at the valley $\xi$. To derive an analytical expression of the Chern number, we neglect the tilt term $w_0$, since it does not appear in the TRS breaking condition (Eq.10). The Hamiltonian around the Dirac points (Eq.13), could then be written as:
\[
H_{\xi}(\vec{q}) = \vec{h}_{\xi}(\vec{q}), \vec{\sigma},
\] (18)

with $\vec{h}_{\xi}(\vec{q}) = (\xi w_x q_x, w_y q_y, m_{\xi}) \equiv |\vec{h}_{\xi}(\vec{q})|\vec{n}_{\xi}(\vec{q})$.

The corresponding Chern number reads as:
\[
C_{\xi} = \frac{1}{2\pi} \int \Omega_{\xi}(\vec{q}) d^2\vec{q},
\] (19)

where $\Omega_{\xi}$ is the component of the Berry curvature along the unitary vector $\vec{n}_{\xi}(\vec{q})$:
\[
\Omega_{\xi} = \frac{1}{\pi} \left[ \partial_{\vec{q}_x} \vec{n}_{\xi}(\vec{q}) \times \partial_{\vec{q}_y} \vec{n}_{\xi}(\vec{q}) \right] \cdot \vec{n}_{\xi}(\vec{q}).
\] (13)

Straightforward calculations give:
\[
C = \frac{1}{2} \left[ \text{sign}(m_{\pm}) - \text{sign}(m_{-}) \right],
\] (20)

This expression is reminiscent of the HM one for undeformed lattice, however the mass terms are, now, strain dependent (Eq.16). In the following, we discuss the corresponding phase diagram.

**C. Haldane model under strain: Phase diagram**

In figure 2, we represent the phase diagram of the HM under uniaxial strain as a function of $\frac{M}{2t_2}$ and $\Phi$ for different strain values. The calculations are done for $t_2 = 0.1t$. The phase boundaries between the trivial ($C = 0$) and the topological ($C = \pm 1$) phases corresponds to the case where one Dirac points is gaped ($m_{\xi} \neq 0$) and the other is not ($m_{\xi} = 0$), which yields to the condition:
\[
\frac{M}{2t_2} = \pm |\sin \Phi \sin 2\theta - \frac{2t'_2}{t_2} \sin \Phi' \sin \theta|,
\] (21)

where $\theta$ and $\Phi'$ are strain dependent (Eqs.5 and 15).

Figure 2 shows that the topology is affected by the deformation. For a compressive strain, the extent of the topological phases is reduced as the strain amplitude increases. At the critical value of $\epsilon = -0.5$, the system turns to a trivial insulator since the Dirac cones merge for this strain amplitude and the electrons loose their Dirac character\(^{45}\). For a tensile strain, the number of topological lobes increases.

According to figure 2, the strain could drive a topological phase, of the undeformed lattice, into a trivial one. In particular, at a tensile strain of $\epsilon = 0.15$, the topological phase with $C = -1$ (for $M = t_2$ and $\Phi = \frac{11}{12}\pi$) switches to a trivial phase ($C = 0$). On the other hand, a topological state with $C = -1$ ($M = 0$ and $\Phi = \frac{11}{12}\pi$) could turn to an other topological phase with an opposite Chern number by applying a tensile deformation of the order of $\epsilon = 0.15$. These results are summarized in figure 3 where we depicted the phase diagram as a function of $\Phi$ and the strain amplitude $\epsilon$. The color map indicates the value of the sublattice potential $M$. This figure shows that the phase boundaries are strain dependent and that a compressive strain compete with the non-trivial topological character of the system. However, a tensile deformation furthers the formation of topological states and
FIG. 2. Phase diagram of the HM for different strain amplitudes. The case of compressive (tensile) strain is shown in the upper (lower) panel. For the strain amplitudes $\epsilon = 10, 15\%$, the Chern number of the phase around $M = 0$ and $\Phi = \pi$ ($\Phi = -\pi$) is $C = 1$ ($C = -1$). Calculations are done for $t_2 = 0.1t$.

the transitions between phases with opposite Chern numbers. These features may lead to a strain tuned topology with switchable edge currents, which could be of a great interest for quantum computing\textsuperscript{49}.

It is worthwhile to note that the $2\pi$ periodicity of the Haldane phase diagram as a function of $\Phi$ is not conserved, under strain, by taking $\Phi' \neq \Phi$ as in Eq.5, which results in a nonvanishing Chern number for $\Phi = \pi$ and $M = 0$ (Fig.2). Actually, according to Eq.21, the strain dependence of the phase boundaries in figure 2 is not only due to the presence of different phase $\Phi$ and $\Phi'$ (Eq.5). The Haldane phase diagram will be affected by the uniform uniaxial strain even if $\Phi = \Phi'$, since the line boundaries will depend on the strain amplitude through the ratio $t_2'/t_2$ (Eq.21). This feature is shown in figure 4 where we depicted the Haldane phase diagram under a uniaxial strain in the cases where $\Phi = \Phi'$ and $\Phi \neq \Phi'$.

This figure shows that, taking $\Phi = \Phi'$ restores the $2\pi$ periodicity of the Haldane phase diagram. However, the topology is still affected by the strain as in the case where $\Phi \neq \Phi'$ (Eq.5).

FIG. 3. Evolution of the topological phases of the HM under strain. The point $(M = 0, \Phi = 0)$, at which the transition between two topological phases take place in the undeformed lattice, is found to be shifted by the strain to $(M = 0, \Phi \neq 0)$.

The transition boundary line for $\Phi = \frac{11}{12}\pi$ of figure 2 is shown in figure 5 as function of the strain amplitude. The figure shows, that at a given non vanishing mass value $M$, the system could undergo transitions between phases with different Chern numbers by tuning the strain. Moreover, the strain may change the sign of the Chern number of a given topological phase. As a consequence, the corresponding edge currents direction of propagation is expected to be switchable by the strain, which may open the way to the strain engineering of the
edge currents.

FIG. 5. Phase diagram of the HM as a function of the strain amplitude for $\Phi = \frac{14}{15}\pi$ and $t_2 = 0.1t$. The dots indicate the values of $M$ at which the topological gap closes in one valley.

In figure 2, the line boundaries correspond to the regime where the topological gap opens in one valley and closes in the other. The strain dependence of this gap is represented in figure 6 which shows that a uniform uniaxial strain could tune the topological gap. This behavior is different from that found in the case of HM under a nonuniform strain where the gap is found to be weakly modified by the strain$^{31,32}$

FIG. 6. Strain dependence of the topological gaps of the Haldane model (Eq. 16) for $t_2 = 0.1t$, $M = t_2$ and $\phi = \frac{14}{15}\pi$ at the Dirac points $D$ and $D'$.

It is interesting to address the behavior of the topological phases when the Dirac cones merge at the critical strain value of $\epsilon = -0.5$ (Eq. 12). We plot, in figure 7, the evolution, as a function of strain, of the phase boundary of the topological state obtained at $\Phi = \frac{\pi}{2}$. This figure shows that at the merging point, the system turns to a trivial state as it is expected$^{50}$. On the other hand, at the tensile strain amplitude $\epsilon = 0.5$, transitions between topological phases with opposite Chern numbers take place at finite $M$, which results in a line boundary. In the undeformed HM, such transition occurs only at the point $M = 0$ and $\Phi = 0$. This feature is reminiscent of the result found in the case of the Chern insulator on a square lattice$^{51}$ and in disordered semi-Dirac material$^{23}$. At the critical value $\epsilon = 0.5$, the hopping parameter $t'$ vanishes (Eq. 4) as found in Ref. 23. It worth to stress that this transition line persists if one considers $\Phi' = \Phi$. Such phase boundary could be observed in cold atoms trapped in optical lattices where parameters could be tuned to reach the extreme strain amplitude regime$^{8,52}$

FIG. 7. HM phase diagram as a function of the strain amplitude up to the large strain regimes. The system becomes trivial at the critical value $\epsilon = -0.5$ at which the Dirac cones merge. A boundary line between two topological phases with opposite Chern numbers is found at $\epsilon = 0.5$ for which the hopping term, to the first neighboring atoms, along the strain direction vanishes. Calculations are done for $\Phi = \frac{\pi}{2}$ and $t_2 = 0.1t$.

The generalization of the present work to spinfull systems, may provide insights into the behavior of the edge states of topological insulators subjected to a uniaxial strain$^{34}$. Actually, the strain dependence of the phase $\Phi'$, is reminiscent of the strain dressed intrinsic SOC of a graphene nanoribbon$^{37}$, where the low SOC regime corresponds to the QAH state.

It is worth to note that the phase diagram of Fig.2 is derived within the continuum approximation, which is not accurate$^{12}$. We then present, in the following, a tight-binding (TB) approach to discuss the role of a uniaxial strain on the edge states of a nanoribbon described by the HM.

III. HALDANE MODEL UNDER STRAIN: A TIGHT-BINDING APPROACH

We consider the HM in a strained zigzag nanoribbon deformed along the armchair direction. The ribbon geometry is shown in figure 8(a). We calculate the full band structure within the TB model for a ribbon of a width $W = 60$ atoms along the $y$ axis parallel to the strain
direction.

Figure 8 (a) Geometry of a zigzag nanoribbon of a width $W$ along the armchair edge. The unit cell is shown by the dashed line. (b-e) Electronic band structure of HM within the tight binding approach (right panels) for a zigzag nanoribbon with a width of $W = 60$ atoms along the $y$ direction. Calculations are done for $t_2 = 0.1t$, $M = 0$, $\Phi = \frac{14}{15}\pi$. Figures (b), (c) and (d) correspond, respectively, to the undeformed lattice ($\epsilon = 0$), $\epsilon = 0.1$ at which the topological gap closes, and $\epsilon = 0.15$. Figure (e) represents the case where $M = 0.1t$, $\Phi = \frac{31}{36}\pi$ and $\epsilon = 0.17$ ascribed to a trivial band insulator.

Figure 8 (b) represent the case of the HM on the undeformed lattice for a topological phase, with $M = 0$ and $\Phi = \frac{14}{15}\pi$, for which the gap is purely topological and the Chern number is $C = -1$. The gapless states crossing the gap are ascribed to the chiral edge states. The corresponding eigenfunctions show that these edge modes are localized on the bottom (solid red line) and on the top (blue dashed line) of the ribbon boundaries. By increasing the strain amplitude to $\epsilon_0 = 0.1$, the topological gap closes and the edge states become dispersionless, which corresponds to the phase boundary line in figure 2. For $\epsilon \sim 0.15$, the topological gap reopens and the chiral edge states reappear showing opposite slopes compared to the case $\epsilon < \epsilon_0$, which means that the corresponding edge currents will change signs (Fig.8(d)). This result is consistent with the phase diagram of Fig.2 showing that, for $M = 0$ and $\Phi = \frac{14}{15}\pi$, the Chern number changes from $C = -1$, in the absence of strain, to $C = 1$ under a strain of $\epsilon \sim 0.15$.

Figure 8 (e) shows the behavior of the edge states under strain in the case where $M = 0.1t$ and $\Phi = \frac{31}{36}\pi$. The topological phase ($C = -1$) is tuned, at $\epsilon \sim 0.17$, to a trivial one ($C = 0$) for which the edge states disappear.

Following Reference\textsuperscript{17}, we discuss the relationship between the dispersion of the edge states of a topological phase and the corresponding Chern number.

Figure 9. Probability distributions of the edge states of a zigzag nanoribbon of a width $W = 60$ atoms described by the HM under a strain amplitude of $\epsilon = 0$ (upper panels) and $\epsilon = 0.15$ (lower panels) and for $M = 0$ and $\phi = \frac{14}{15}\pi$. The figures (a) and (b) ((c) and (d)) correspond to a topological phase with a Chern number $C = -1$ ($C = 1$). The insets in figures (b) and (d) give the direction of the edge currents.

Figure 9 represents the energy spectrum of the undeformed system for $M = 0$ and $\Phi = \frac{14}{15}\pi$, which corresponds, according to the Haldane phase diagram to a topological phase with $C = -1$. The probability distributions of the edge states, denoted $A$ and $B$, are represented in Fig.9 (b), which shows that the $A$ ($B$) edge state with the positive (negative) velocity $v_x = \frac{\partial E(\vec{k})}{\partial k_x}$ is localized on the bottom (top) boundary of the ribbon. For a Fermi level above the zero energy, the edge states will give rise to edge currents $I = -e v_x$, $e > 0$ being the elementary charge. These currents, depicted in Figs.9 (b,d), are responsible of the sign of the Chern number since the anomalous Hall conductivity reads as: $\sigma_{xy} = \frac{e^2}{h}C$. In Fig.9 (b) ((d)), the current is negative (positive) which yields to $C = -1$ ($C = +1$), in agreement with the phase diagram obtained in the continuum limit (Fig.2).
IV. MODIFIED HALDANE MODEL UNDER UNIAXIAL STRAIN

We consider a graphene nanoribbon with zigzag edges under a uniform uniaxial strain applied along the armchair direction (denoted $y$ axis). The ribbon has a finite width $W$ along the armchair edge. It was found that such system could exhibit co-propagating-edge states, if described within the mHM where the hopping integrals to the second neighboring atoms are given by the pattern shown in figure 10.

![Diagram](image)

**FIG. 10.** The pattern for the second-neighbor hopping parameters of the mHM under uniaxial strain applied along the armchair direction. The arrow indicate the directions along which the hopping integrals $t_2$ and $t'_2$ acquire positive phase $e^{i\Phi}$ and $e^{i\Phi'}$ respectively.

Using the tight binding approach, we depict in figure 11 the electronic band structure of a ribbon of width $W = 60$ atoms, at different strain amplitudes, for $M = 0$ and $\Phi = \frac{14}{15}\pi$ as in the HM. Figure 11 (a) shows that, in the undeformed lattice, the antichiral edge states have the same velocity which is counterbalanced by the bulk mode crossed by the Fermi energy. By increasing the strain amplitude, the dispersion of the antichiral edge modes is modified and eventually disappear at a critical value $\epsilon_0 = 0.1$, and the system is tuned into a trivial semi-metal. As the strain increases beyond $\epsilon_0$, the antichiral edge states appear again with opposite velocity compared to the case $\epsilon < \epsilon_0$. This feature may pave the way to realize strain-tuned antichiral edge currents, which can be tested in the 2D metal transition dichalcogenide material WSe$_2$. It is worth to note that this material exhibits, contrary to the mHM, a bulk bandgap. However, as mentioned in Reference 42, by tuning the doping, this material could support a current in one edge counterpropagating with a bulk current as in mHM.

![Band diagram](image)

**FIG. 11.** Band structure of a graphene zigzag nanoribbon under uniaxial strain described by the mHM at different strain amplitudes. The calculations are done for a ribbon of a width of $W = 60$ atoms, $t_2 = 0.1t$, $\Phi = 14/15\pi$. Figure (a-d) correspond, respectively, to the undeformed lattice ($\epsilon = 0$), $\epsilon = -0.08$, $\epsilon = \epsilon_0 = 0.1$ and $\epsilon = 0.15$. At the critical value of $\epsilon_0 = 0.1$, the edge modes become dispersionless and above this value their velocity changes sign compared to the case $\epsilon < \epsilon_0$. The dashed line indicates the position of the Fermi level.

V. CONCLUSIONS

We discussed the robustness of the topological phases of the Haldane and the modified Haldane models against a uniform uniaxial strain. We considered a zigzag hexagonal nanoribbon exhibiting dispersionless edge states in the trivial phase and in the absence of strain. Using the continuum limit approximation and the tight binding approach, we found that the topology of these models could be tuned by the strain. At a critical value of the strain amplitude, a topological phase can be turned into a trivial one. By varying the strain amplitude, transitions between phases, with different Chern numbers, could take place. Our results show that the line boundary of the Haldane phase diagram, where one valley becomes gapless, is strain dependent. A compressive strain is found to reduce the extent of the topological phases whereas a tensile one is expected to increase the number of the topological lobes. We also showed that the dispersion of the topologically protected edge states in the HM could be modified by the strain. The directions of propagation of the latter and the corresponding Chern number signs may be reversed by the strain.

Regarding the antichiral edge modes of the mHM, we found that the uniaxial strain could switch their direction of propagation, which may give rise to strain-tuned edge currents. A possible realization of this effect could be achieved in 2D metal transition dichalcogenides, where antichiral edge modes are expected to be observable.42
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